

High Performance Regulators for PCs Switching Regulator with MOSFET for DDR-SDRAM Cores

BD95500MUV

No.10030ECT21

Description

BD95500MUV is a switching regulator with high output current (up to 6A) which can achieve low output voltage (0.7V to 5.0V) from a wide input voltage range (3V to 20V). High efficiency for the switching regulator can be realized by utilizing an internal N-MOSFET power transistor. A new technology called H³Reg[™] is a Rohm proprietary control method to realize ultra high transient response against load change. SLLM (Simple Light Load Mode) technology is also integrated to improve efficiency in light load mode, providing high efficiency over a wide load range. For protection and ease of use, the soft start function, variable frequency function, short circuit protection function with timer latch, over voltage protection function, and power good function are all built in. This switching regulator is specially designed for sets of various kinds.

Features

- Integrated low ON resistance N-MOSFET (TYP. 50mΩ)
 H³Reg[™] DC/DC converter controller
- 3) Adjustable Simple Light Load Mode (SLLM), and forced continuous mode
- 4) Thermal Shut Down (TSD), Under Voltage LockOut (UVLO), Adjustable Over Current Protection (OCP), Over Voltage Protection (OVP), Short Circuit Protection(SCP) built-in
- 5) Soft start function to minimize rush current during startup
- 6) Adjustable switching frequency (f=200KHz~1000KHz)
- 7) Built-in output discharge function
- 8) VQFN040V6060 Package
- 9) Tracking Function
- 10) Integrated boot strap diode
- 11) Power Good function

Applications

Mobile PC, Desktop PC, LCD-TV, Digital Components, etc

Maximum Absolute Ratings (Ta=25°C)

| Parameter | Symbol | Ratings | Unit |
|-----------------------------|-----------------|--------------------|------|
| Input Voltage 1 | VCC | 7 *1 | V |
| Input Voltage 2 | VDD | 7 *1 | V |
| Input Voltage 3 | VIN | 24 ^{*1} | V |
| BOOT Voltage | BOOT | 30 | V |
| BOOT-SW Voltage | BOOT-SW | 7 | V |
| LG Voltage | LG | VDD | V |
| REF Voltage | REF | VCC | V |
| Output Voltage | VOUT/Is+/Is- | VCC | V |
| ILIM/SS/FS/MODE Voltage | ILIM/SS/FS/MODE | VCC | V |
| VREG Voltage | VREG | VCC | V |
| EN Input Voltage | EN | 7 | V |
| Output Current (Average) | Isw | 6 | А |
| Power Dissipation 1 | Pd1 | 0.54 *2 | W |
| Power Dissipation 2 | Pd2 | 1.00 ^{*3} | W |
| Power Dissipation 3 | Pd3 | 3.77 *4 | W |
| Power Dissipation 4 | Pd4 | 4.66 *5 | W |
| Operating Temperature Range | Topr | -10~+100 | °C |
| Storage Temperature Range | Tstg | -55~+150 | °C |
| Junction Temperature | Tjmax | +150 | °C |

*1 Not to exceed Pd, ASO, and Tjmax=150°C.

*2 Reduced by 4.3mW for each increase in Ta of 1°C over 25°C (when don't mounted on a heat radiation board)

*3 Reduced by 8.0mW for increase in Ta of 1°C over 25°C. (when mounted on a board 70.0mm × 70mm × 1.6mm Glass-epoxy PCB which has 1 layer. (Copper foil area : 0mm²))

(All copper foil area : 5505mm²))

| Deremeter | Cumphol | Rat | ings | l loit |
|---------------------------|---------|------|------|--------|
| Parameter | Symbol | MIN | MAX | Unit |
| Input Voltage 1 | VCC | 4.5 | 5.5 | V |
| Input Voltage 2 | VDD | 4.5 | 5.5 | V |
| Input Voltage 3 | VIN | 3.0 | 20 | V |
| BOOT Voltage | BOOT | 4.5 | 25 | V |
| SW Voltage | SW | -0.7 | 20 | V |
| BOOT-SW Voltage | BOOT-SW | 4.5 | 5.5 | V |
| MODE Input Voltage | MODE | 0 | 5.5 | V |
| EN Input Voltage | EN | 0 | 5.5 | V |
| Output Adjustable Voltage | REF | 0.7 | 2.0 | V |
| Is Input Voltage | ls+/ls- | 0.7 | 2.7 | V |
| MIN ON Time | Tonmin | - | 200 | nsec |

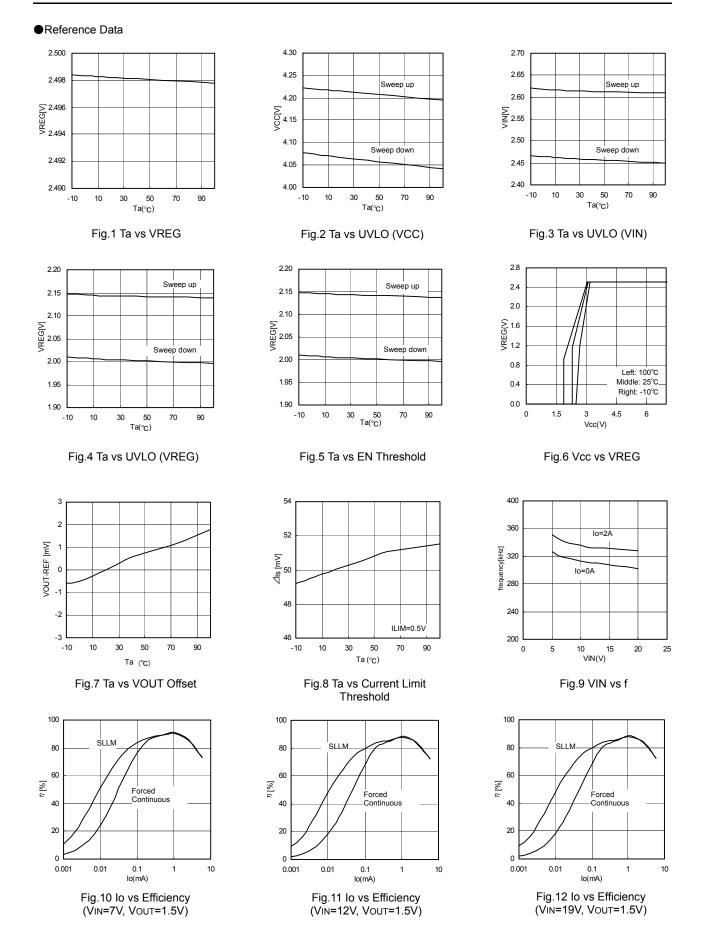
Operating Conditions (Ta=25°C)

*This product should not be used in a radioactive environment.

•Electrical characteristics

(Unless otherwise noted, Ta=25°C, VCC=5V, VDD=5V, EN / MODE=5V, VIN=12V, REF=1.8V, RFS=68kΩ)

| Parameter | Symbol | | Limit | | Unit | Condition |
|------------------------------------------------|------------|------------|------------|------------|---------|----------------------------------------|
| | Cymbol | Min. | Тур. | Max. | Onic | Condition |
| Whole Device] | 1 | I | | | 1 | |
| Vcc Bias Current | Icc | - | 1200 | 2000 | μA | |
| VIN Bias Current | lin | - | 100 | 200 | μA | |
| Vcc Standby Current | Iccstb | - | 0 | 10 | μA | EN=0V |
| VIN Standby Current | linstb | - | 0 | 10 | μA | EN=0V |
| EN Low Voltage | Enlow | GND | - | 0.8 | V | |
| EN High Voltage | Enhigh | 2.3 | - | 5.5 | V | |
| EN Bias Current | len | - | 7 | 10 | μA | |
| VREG Voltage | Vreg | 2.475 | 2.500 | 2.525 | V | Ireg=0 to 500uA, Ta=-10°C to 100°C* |
| Under Voltage Locked Out] | | | | | | |
| Vcc Threshold Voltage | Vcc_UVLO | 4.1 | 4.3 | 4.5 | V | Vcc:Sweep up |
| Vcc Hysteresis Voltage | dVcc_UVLO | 100 | 160 | 220 | mV | Vcc:Sweep down |
| VIN Threshold Voltage | Vin_UVLO | 2.4 | 2.6 | 2.8 | V | VIN:Sweep up |
| Vin Hysteresis | dVin_UVLO | 100 | 160 | 220 | mV | VIN:Sweep down |
| VREG Threshold Voltage | Vreg_UVLO | 2.0 | 2.2 | 2.4 | V | VREG:Sweep up |
| VREG Hysteresis Voltage | dVreg_UVLO | 100 | 160 | 220 | mV | VREG:Sweep down |
| H ³ REG [™] Control Block] | | ı | 1 | 1 | | · · |
| ON Time | Ton | 400 | 500 | 600 | nsec | |
| MAX ON Time | Tonmax | - | 3 | 6.0 | µsec | |
| MIN OFF Time | Toffmin | - | 450 | 550 | nsec | |
| FET Block] | | I | I | I | | I |
| High Side ON Resistance | HGhon | - | 50 | 80 | mΩ | |
| Low Side ON Resistance | HGlon | - | 50 | 80 | mΩ | |
| SCP Block] | | | | | | |
| SCP Start up Voltage | Vscp | REF × 0.60 | REF × 0.70 | REF × 0.80 | V | |
| Delay Time | Tscp | - | 1.0 | 2.0 | ms | |
| OVP Block] | | | | | | |
| OVP Detect Voltage | Vovp | REF × 1.16 | REF × 1.2 | REF × 1.24 | V | |
| Soft Start Block] | | | | | - | |
| Charge Current | lss | 2 | 4 | 6 | μA | |
| Discharge Current | Idis | 0.5 | 1.0 | 2.0 | μA | |
| Standby Voltage | Vss_stb | - | - | 50 | mV | |
| Over Current Protection Block] | V33_3LD | _ | _ | 50 | 111.0 | |
| Current Limit Threshold 1 | llim1 | 40 | 50 | 60 | mV | ILIM=0.5V , Ta=-10°C to 100°C |
| Current Limit Threshold2 | llim2 | 160 | 200 | 240 | mV | ILIM=2.0V |
| Vout Setting] | | | | | | |
| Vour Offset Voltage 1 | Voutoff1 | REF-10m | REF | REF+10m | V | Ta=-10°C to 100°C |
| Vout Bias Current | Ivout | -100 | 0 | 100 | nA | |
| REF Bias Current | Iref | -100 | 0 | 100 | nA | |
| Is+ Input Current | lls+ | -1 | 0 | 1 | μA | ls+=1.8V |
| Is- Input Current | lls- | -1 | 0 | 1 | μA | Is-=1.8V |
| MODE Block] | | | | | P** , | |
| SLLM Threshold | VthsLLM | VCC-0.5 | _ | VCC | V | |
| Forced Continuous Mode | VthCONT | GND | - | 0.5 | V | |
| Input Impedance | RMODE | | 400 | 0.0 | ν kΩ | |
| Power Good Block] | RMODE | - | 400 | - | K77 | <u> </u> |
| = | VoutDI | | | DEEVOOR | V | |
| VOUT Power Good Low Voltage | VoutPL | REF × 0.85 | REF × 0.90 | REF × 0.95 | V | |
| VOUT Power Good High Voltage | VoutPH | REF × 1.05 | REF × 1.10 | REF × 1.15 | V | |



Reference Data

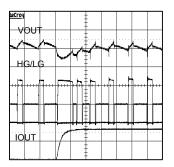


Fig.13 Transient Response (VIN=7V)

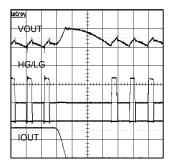
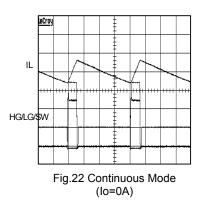


Fig.16 Transient Response (VIN=7V)

| VOUT | | 1 | | |
|----------|-----------------------------------------|---------|---|--------------|
| /~~ | - Aun | | | |
| <u> </u> | | Į | | |
| HG/LG | +++++++++++++++++++++++++++++++++++++++ | ļ | | : ::: |
| | | ŧ | | |
| | | Į. | | |
| | 1000 | HAMMM . | A | |

Fig.19 SLLM Mode (IOUT=0A)



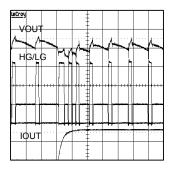


Fig.14 Transient Response (VIN=12V)

| VOU | r Jul | /************************************* | | \sim | / | M | .∧- |
|------|----------|----------------------------------------|-----|--------|---|---|-----|
| HG/L | Ģ | | | 'n | | n | ň |
| | | | | ++++ | | | |
| | | | Ē., | | | | |
| 100 | - | ··· ···· | | | | | |

Fig.17 Transient Response (VIN=12V)

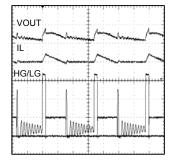
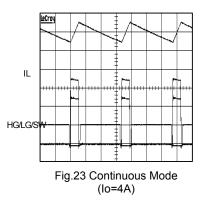


Fig.20 SLLM Mode (IOUT=0.4A)



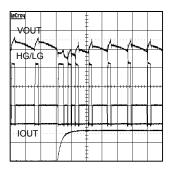


Fig.15 Transient Response (VIN=19V)

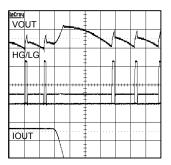


Fig.18 Transient Response (VIN=19V)

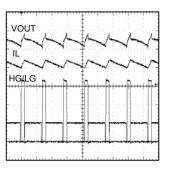
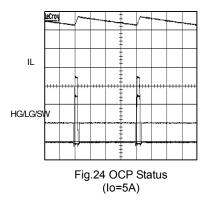
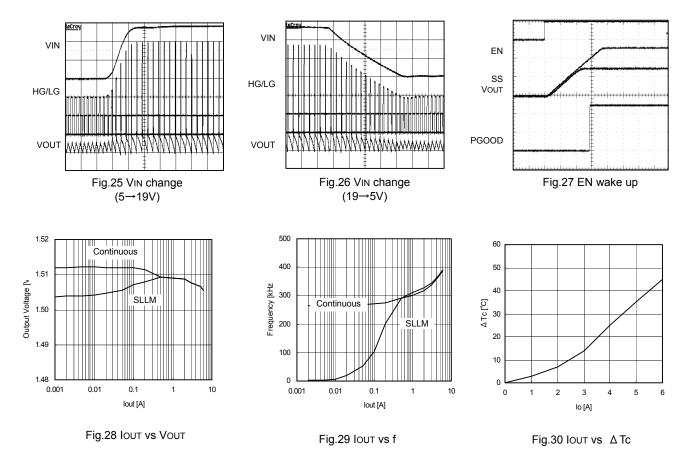


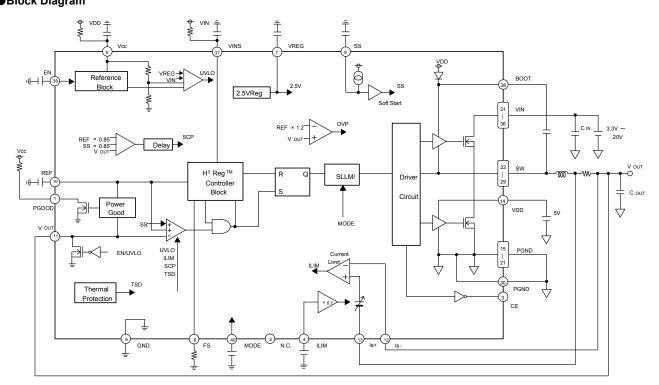
Fig.21 SLLM Mode (IOUT=1A)



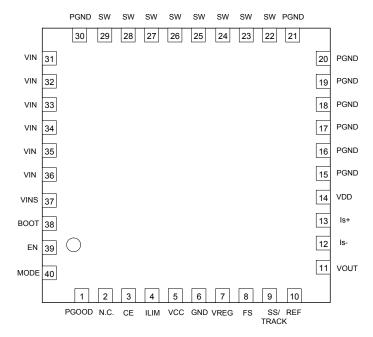
Reference Data



Block Diagram



Pin Configuration



^{*}Connect the bottom side (FIN) to the ground terminal

Pin Function Table

| PIN No. | PIN name | PIN function |
|---------|----------|------------------------------------------------------------------|
| 1 | PGOOD | Power Good Output Pin(+/-10% Window) |
| 2 | N.C. | - |
| 3 | CE | Ceramic Capacitor Reactive Pin |
| 4 | ILIM | Current Limit Setting Pin |
| 5 | VCC | Power Supply Input pin (Control Block) |
| 6 | GND | Sense GND |
| 7 | VREG | IC Reference Voltage (2.5V/500uA) |
| 8 | FS | Switching Frequency Adjustable Pin ($30k \sim 100k \Omega$) |
| 9 | SS/TRACK | Soft Start Setting Pin (w/ Capacitor)/Tracking Voltage Input Pin |
| 10 | REF | Vo Setting Pin |
| 11 | VOUT | Output Voltage Sense Pin |
| 12 | ls- | Current Sense Pin - |
| 13 | ls+ | Current Sense Pin + |
| 14 | VDD | FET Driver Power Supply Pin (5V Input) |
| 15-21 | PGND | Power GND Pin |
| 22-29 | SW | High Side FET Source Pin |
| 30 | PGND | Power GND Pin |
| 31-36 | VIN | Battery Voltage Input pin (3.3~20V Input) |
| 37 | VINS | Battery Voltage Sense pin |
| 38 | BOOT | HG Driver Power Supply Pin |
| 39 | EN | Enable Input pin (IC ON when High) |
| 40 | MODE | Control Mode Adjustment Pin Low: Continuous High: SLLM |
| bottom | FIN | Substrate connection |

Pin Descriptions

• VCC (5 Pin)

This is the power supply pin for IC internal circuits, except the FET driver. The input supply voltage range is 4.5V to 5.5V. It is recommended that a $10\Omega/0.1$ µF C-R filter be put in this pin from VDD rail.

• EN (39 Pin)

When EN pin voltage is at least 2.3V, the status of this switching regulator becomes active. Conversely, the status switches off when EN pin voltage goes lower than 0.8V and circuit current becomes 0µA.

• VDD (14 Pin)

This is the power supply pin to drive the LOW side FET and for Boot-strap diode. It is recommended that a $1\sim10\mu$ F bypass capacitor be established to compensate for rush current during the FET ON/OFF transition.

• VREG (7 Pin)

This is the reference voltage output pin. The voltage is 2.5V, with 500uA current ability. It is recommended that a 0.22~1µF capacitor (X5R or X7R) be established between VREG and GND (6 Pin). When REF is not adjusted from the external voltage supply, the REF voltage can be adjusted using the external resistor divider of VREG.

• REF (10 Pin)

This is the output voltage adjustment pin by resistor divider network from VREG pin ($0.7\sim2.0V$). It is also very convenient for synchronizing external voltage supply. The IC controls the output voltage (REF \Rightarrow VOUT).

· ILIM (4 Pin)

BD95500MUV detects the voltage between Is+ pin and Is- pin and limits the output current (OCP). Voltage equivalent to 1/10 of the ILIM voltage is the voltage drop of external current sense resistor. A very low current sense resistor or inductor DCR can also be used for this platform.

· SS/TRACK (9 Pin)

This is the adjustment pin to set the soft start time. SS voltage is low during standby status. When EN is ON, the soft start time can be determined by the SS charge current and capacitor between SS-GND. Until SS reaches REF voltage, the output voltage is equivalent to SS voltage. And also this pin enables to operate tracking function. The output voltage keeps track of a power supply rail by connecting $10k\Omega$ resistance between the power supply rail and SS/TRACK pin.

VINS (37 Pin)

The duty cycle is determined by input voltage and controls output voltage. In other words, the output voltage is affected by input voltage. Therefore, when VINS voltage fluctuates, the output voltage becomes also unstable. Since the VINS line is also the input voltage of the switching regulator, stability depends on the impedance of the voltage supply. It is recommended to establish a bypass capacitor or CR filter suitable for the actual application.

• FS (8 Pin)

This is the pin to adjust the switching frequency with the resistor. It is recommended that a resistor be established to GND (6 pin). The frequency range is from 200kHz to 1000kHz.

Is+ (13 pin), Is- (12 pin)

These pins are connected to both sides of the current sense resistor to detect output current. The voltage drop between Is+ and Is- is compared with the voltage equivalent to 1/10 of ILIM voltage. When this voltage drop hits the specified voltage level, the output voltage is OFF. Since the maximum input voltage is 2.7V, set the output voltage by the resistance division value in case the output voltage is 2.7V or more.

BOOT (38 pin)

This is the voltage supply to drive the high side FET and a Diode for BOOT strap function is built in. The maximum absolute ratings are 30V (from GND) and 7V (from SW). BOOT voltage swings between (VIN+Vcc) and Vcc during active operation.

PGOOD (1 pin)

This pin is output pin for Power Good. It is open drain pin and recommended to connect to other power supply through the pull-up resistance (about $100k\Omega$).

• CE (3 pin)

This pin is for the ceramic capacitor. It is useful to utilize low ESR capacitor for output capacitor.

• MODE (40 pin)

This is the control mode changeable pin. The status is Low : continuous mode, the status is High : SLLM[™].

• VOUT (11 pin)

This is the monitor pin for output voltage. This IC controls the voltage in the status of REF = VOUT. When output voltage is required 2V or more, set the output voltage by the resistance division value.

• SW (22-29 pin)

This is connected pin for coil. SW voltage swings between VIN and GND. It is recommended to connect by heavy and short pattern to coil.

VIN (31-36 pin)

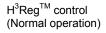
This is input power supply pin. Recommend input voltage is 3.3V to 20V. Connect the input capacitor against PGND directly.

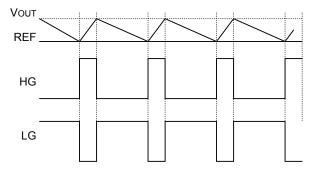
• PGND (15-21, 30 pin)

This is power ground pin. It is recommended to connect by heavy and short pattern. Connect in reverse side of IC when connecting to GND (6 pin).

Explanation of Operation

The BD95500MUV is a switching regulator controller incorporating ROHM's proprietary H³RegTM CONTROLLA control system. When Vout drops due to a rapid load change, the system quickly restores Vout by extending the ton time interval. Thus, it serves to improve the regulator's transient response. Activating the Light Load Mode will also exercise Simple Light Load Mode (SLLM) control when the load is light, to further increase efficiency.



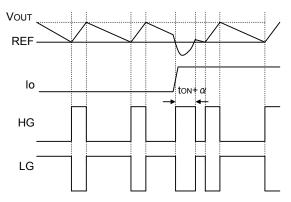


When VOUT falls to a threshold voltage (REF), the drop is detected, activating the H^3Reg^{TM} CONTROLLA system.

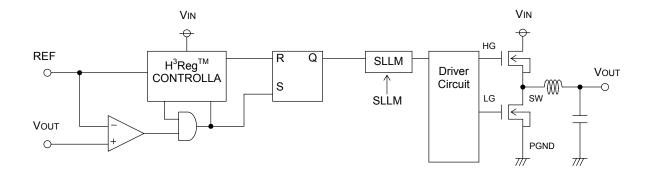
$$T_{ON} = \frac{REF}{V_{IN}} \times \frac{1}{f} [sec] \cdot \cdot \cdot (1)$$

HG output is determined by the formula above.

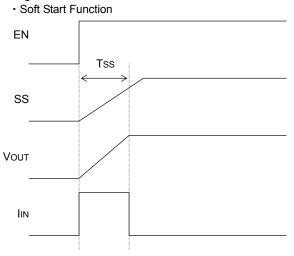
(VOUT drops due to a rapid load change)



When VOUT drops due to a rapid load change, and the voltage remains below VREF after the programmed ton time interval has elapsed, the system quickly restores VOUT by extending the ton time, improving the transient response.







Soft start is exercised with the EN pin set high. Current control takes effect at startup, enabling a moderate output voltage "ramping start." Soft start timing and incoming current are calculated with formulas (2) and (3) below.

Soft start time

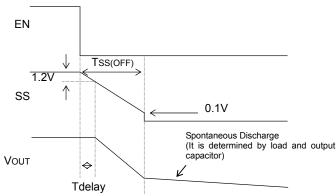
Tss=
$$\frac{\text{REF} \times \text{Css}}{4\mu A(\text{typ})} \text{ [sec] } \cdot \cdot \cdot (2)$$

Rush current

$$IIN (ON) = \frac{Co \times V_{OUT}}{Tss} [A] \cdot \cdot \cdot (3)$$

(Css: Soft start capacitor; Co: Output capacitor)





Soft stop is exercised with the EN pin set low. Current control takes effect at startup, enabling a moderate output voltage. Soft start timing and incoming current are calculated with formulas (4) below.

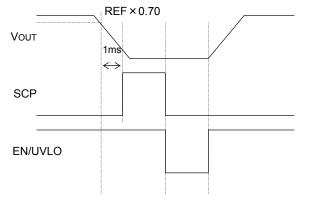
Soft stop time

$$T_{SS (OFF)} = \frac{(REF+2V_{BE}) \times C_{SS}}{1\mu A (typ)} \quad [sec] \cdot \cdot \cdot (4)$$

∆Vss= 1.2[V] (typ)

Tdelay =
$$\frac{Css}{1\mu A(typ)}$$
 [sec] · · · (5)

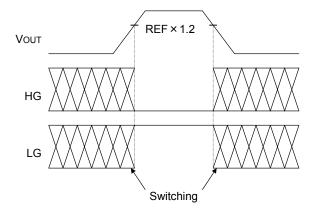
Timer Latch Type Short Circuit Protection



When output voltage (Is-) falls to $\text{REF} \times 0.7$ or less, SCP comparator inside IC is exercised.

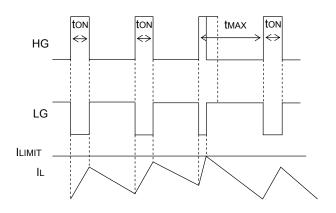
If the status of High is continued 1ms or more (programmed time inside IC), the IC goes OFF. It can be restored either by reconnecting the EN pin or disabling UVLO.

Output Over Voltage Protection



When output rise to or above REF \times 1.2, output over voltage protection is exercised, and low side FET goes up maximum for reducing output. (LG=High, HG=Low). When output falls, it returns to the standard mode.

Over current protection circuit

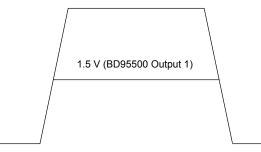


During the normal operation, when Vout becomes less than REF Voltage, HG becomes High during the time ton (P9). However, when inductor current exceeds I_{LIMIT} threshold, HG becomes OFF.

After MAX ON TIME, HG becomes ON again if the output voltage is lower than the specific voltage level and I_L is lower than I_{LIMIT} level.

Synchronous operation with external power supply

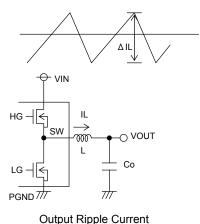
3.3V (External Power Supply)



These power supply sequences are realized to connect SS pin to other power supply output through the resistance ($10k\Omega$).

External Component Selection

1. Inductor (L) selection



The inductor value is a major influence on the output ripple current. As formula (5) below indicates, the greater the inductor or the switching frequency, the lower the ripple current.

$$\Delta IL = \frac{(VIN-VOUT) \times VOUT}{L \times VIN \times f} \quad [A] \cdot \cdot \cdot (4)$$

The proper output ripple current setting is about 30% of maximum output current.

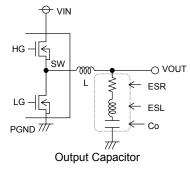
$$\Delta$$
 IL=0.3 × IOUTmax. [A] · · · (5)

$$L = \frac{(VIN-VOUT) \times VOUT}{I \times VIN \times f} \quad [H] \cdot \cdot \cdot (6)$$

(Δ IL: output ripple current; f: switch frequency)

- *Passing a current larger than the inductor's rated current will cause magnetic saturation in the inductor and decrease system efficiency. In selecting the inductor, be sure to allow enough margin to assure that peak current does not exceed the inductor rated current value.
- *To minimize possible inductor damage and maximize efficiency, choose a inductor with a low (DCR, ACR) resistance.

2. Output Capacitor (Co) Selection



When determining the proper output capacitor, be sure to factor in the equivalent series resistance and equivalent series inductance required to set the output ripple voltage 20mV or more. In selecting the limit of inductor, be sure to allow enough margin for output voltage.

Output ripple voltage is determined as in formula (7) below.

 $\Delta VOUT = \Delta IL \times ESR + ESL \times \Delta IL / TON \cdot \cdot \cdot (7)$

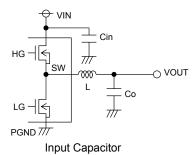
(Δ IL: Output ripple current; ESR: Co equivalent series resistance, ESL: equivalent series inductance)

Please give due consideration to the conditions in formula (8) below for output capacity, bear in mind that output rise time must be established within the soft start time frame.

$$Co \leq \frac{TSS \times (Limit-IOUT)}{VOUT} \cdots (8)$$
Tss: Soft start time (See formula (2) in P10)
Limit: Over current detection (See formula (10)(11) in P13)

Note: Improper capacitor may cause startup malfunctions

3. Input Capacitor (Cin) Selection

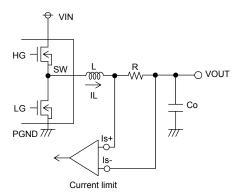


The input capacitor selected must have low enough ESR resistance to fully support large ripple output, in order to prevent extreme over current. The formula for ripple current IRMS is given in (9) below.

IRMS=IOUT ×
$$\frac{\sqrt{VIN (VIN-VOUT)}}{VIN}$$
 [A] · · · (9)
Where VIN=2 × VOUT, IRMS= $\frac{IOUT}{2}$

A low ESR capacitor is recommended to reduce ESR loss and maximize efficiency.

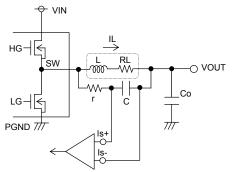
4. Setting Detection Resistance



The over current protection function detects the output ripple current peak value. This parameter (setting value) is determined as in formula (10) below.

ILMIT=
$$\frac{VILIM \times 0.1}{R}$$
 [A] · · · (10)

(VILIM: ILIM voltage, R: Detection resistance)

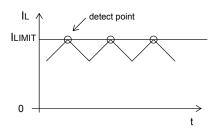


Current limit

When the over current protection is detected by DCR of coil L, this parameter (setting value) is determined as in formula (11) below.

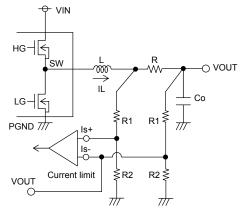
$$ILMIT=VILIM \times 0.1 \times \frac{r \times C}{L} \quad [A] \cdot \cdot \cdot (11)$$

 $(RL = \frac{L}{r \times C})$ (VILIM:ILIM voltage, RL: the DCR value of coil)



As soon as the voltage drop between Is+ and Is- generated by the inductor current becomes specific threshold, the gate voltage of the high side MOSFET becomes low.

Since the peak voltage of the inductor ripple current is detected, this operation can sense high current ripple operation caused by inductance saturated rated current and lead to high reliable systems.



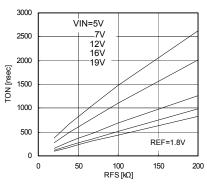
When the output voltage is 2.7V or more, use the resistance for setting output voltage like left figure, for Is+ and Is-.

According to the setting value above, ILIMIT setting current is in proportion to the divided ratio.

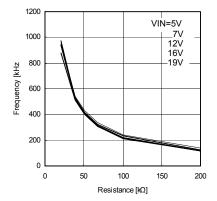
ILMIT=
$$\frac{\text{R1+R2}}{\text{R1}} \times \frac{\text{VLIMIT} \times 0.1}{\text{R}}$$
 [A] · · · (12)

(VILIM: ILIM voltage R: Detection resistance)

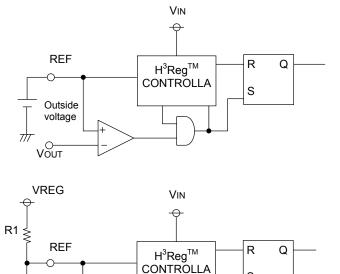
5.Setting frequency







6. Setting standard voltage (REF)



The On Time (toN) at steady state is determined by resistance value connected to FS pin.

But actually SW rising time and falling time come up due to influence of the external MOSFET gate capacity or switching speed and toN is increased.

The frequency is determined by the following formula after ton, input current and the REF voltage are fixed.

 $\frac{1}{V_{\text{IN}} \times \text{ton}} \cdot \cdot \cdot (13)$

F=

Consequently, total frequency becomes lower than the formula above.

TON is also influenced by Dead Time around the output current 0A area in continuous mode.

This frequency becomes lower than setting frequency. It is recommended to check the steady frequency in large current area (at the point where the coil current doesn't back up).

It is available to synchronize setting the reference voltage (REF) with outside supply voltage [V] by using outside power supply voltage.

It is available to set the reference voltage (REF) by the resistance division value from VREG in case it is not set REF from an external power supply.

 $REF = \frac{R2}{R1+R2} \times VREG [V] \cdot \cdot \cdot (14)$

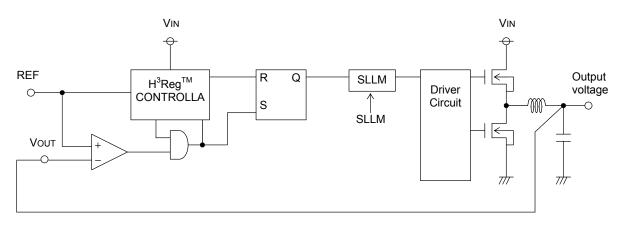
T h

VOUT

S

7. Setting output voltage

This IC is operated that output voltage is REF≒Vou⊤. And it is operated that output voltage is feed back to FB pin in case the output voltage is 0.7V to 2.0V.

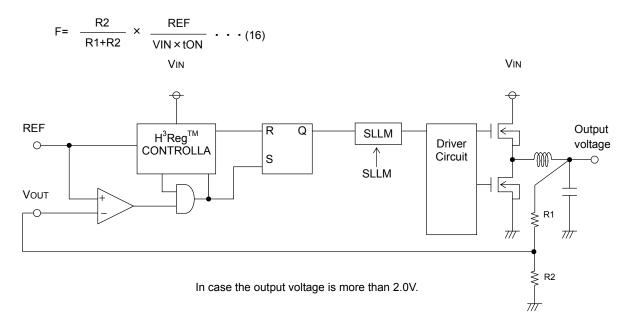


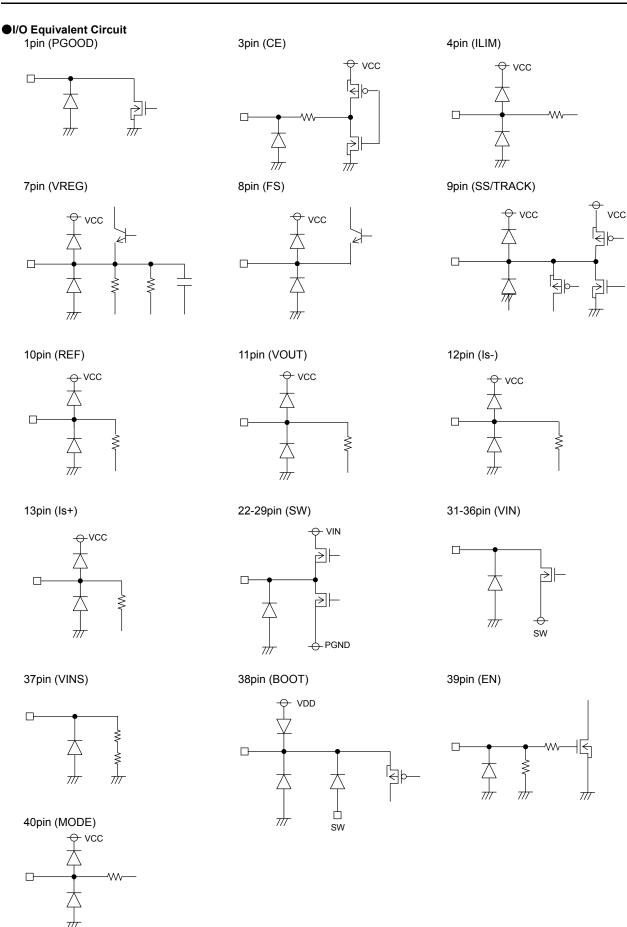
In case the output voltage range is 0.7V to 2.0V.

It is operated that the resistance division value of the output voltage is feed back to Vout pin in case the output voltage is more than 2.0V.

output voltage $\Rightarrow \frac{R1+R2}{R2} \times REF[V] \cdot \cdot \cdot (15)$

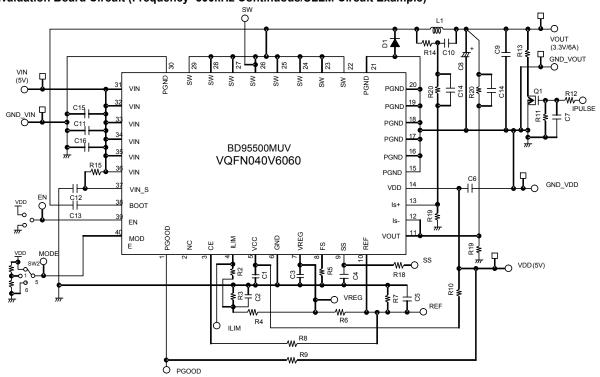
And then the frequency is also in proportion to the divided ratio.





www.rohm.com © 2010 ROHM Co., Ltd. All rights reserved. Downloaded from Elcodis.com electronic components distributor

• Evaluation Board Circuit (Frequency=300kHz Continuous/SLLM Circuit Example)



Evaluation Board Parts List

| | Dould I | | | | | | |
|---------|---------|---------|--------------------|---------|--------|-------------------------|----------------------------|
| Part No | Value | Company | Part name | Part No | Value | Company | Part name |
| U1 | - | ROHM | BD95500MUV | R17 | 100kΩ | ROHM | MCR03 Series |
| D1 | - | ROHM | RB051L-40 | R18 | 1kΩ | ROHM | MCR03 Series |
| L1 | 4.3uH | Sumida | CDEP105NP-4R3MC-88 | R19 | 10kΩ | ROHM | MCR03 Series |
| Q1 | - | - | - | R20 | 12kΩ | ROHM | MCR03 Series |
| R1 | 0Ω | ROHM | MCR03 Series | C1 | 0.1uF | MURATA | GRM18 Series |
| R2 | 0Ω | ROHM | MCR03 Series | C2 | 100pF | MURATA | GRM18 Series |
| R3 | 100kΩ | ROHM | MCR03 Series | C3 | 0.47uF | MURATA | GRM18 Series |
| R4 | 150kΩ | ROHM | MCR03 Series | C4 | 1000pF | MURATA | GRM18 Series |
| R5 | 68kΩ | ROHM | MCR03 Series | C5 | 1000pF | MURATA | GRM18 Series |
| R6 | 100kΩ | ROHM | MCR03 Series | C6 | 10uF | MURATA | GRM21 Series |
| R7 | 150kΩ | ROHM | MCR03 Series | C7 | - | MURATA | GRM18 Series |
| R8 | - | ROHM | MCR03 Series | C8 | 220uF | SANYO or something | functional high polymer |
| R9 | 100kΩ | ROHM | MCR03 Series | C9 | 10uF | MURATA | GRM21 Series |
| R10 | 10Ω | ROHM | MCR03 Series | C10 | 0.1uF | MURATA | GRM18 Series |
| R11 | - | ROHM | MCR03 Series | C11 | 10uF | KYOSERA or something | CM316B106M25A |
| R12 | 10Ω | ROHM | MCR03 Series | C12 | 0.1uF | MURATA | GRM18 Series |
| R13 | | ROHM | MCR03 Series | C13 | 0.1uF | MURATA | GRM18 Series |
| R14 | 1kΩ | ROHM | MCR03 Series | C14 | 100pF | MURATA | GRM18 Series |
| R15 | 1kΩ | ROHM | MCR03 Series | C15 | 10uF | KYOSERA or something | CM316B106M25A |
| R16 | 100kΩ | ROHM | MCR03 Series | C16 | 0.1uF | MURATA | GRM18 Series |

Operation Notes

(1) Absolute maximum ratings

An excess in the absolute maximum ratings, such as supply voltage, temperature range of operating conditions, etc., can break down the devices, thus making impossible to identify breaking mode, such as a short circuit or an open circuit. If any over rated values will expect to exceed the absolute maximum ratings, consider adding circuit protection devices, such as fuses.

(2) Connecting the power supply connector backward

Connecting of the power supply in reverse polarity can damage IC. Take precautions when connecting the power supply lines. An external direction diode can be added.

(3) Power supply lines

Design PCB layout pattern to provide low impedance GND and supply lines. To obtain a low noise ground and supply line, separate the ground section and supply lines of the digital and analog blocks. Furthermore, for all power supply terminals to ICs, connect a capacitor between the power supply and the GND terminal. When applying electrolytic capacitors in the circuit, not that capacitance characteristic values are reduced at low temperatures.

- (4) GND voltage The potential of GND pin must be minimum potential in all operating conditions.
- (5) Thermal design Use a thermal design that allows for a sufficient margin in light of the power dissipation (Pd) in actual operating conditions.
- (6) Inter-pin shorts and mounting errors Use caution when positioning the IC for mounting on printed circuit boards. The IC may be damaged if there is any connection error or if pins are shorted together.
- (7) Actions in strong electromagnetic field Use caution when using the IC in the presence of a strong electromagnetic field as doing so may cause the IC to malfunction.
- (8) ASO

When using the IC, set the output transistor so that it does not exceed absolute maximum ratings or ASO.

(9) Thermal shutdown circuit

The IC incorporates a built-in thermal shutdown circuit (TSD circuit). The thermal shutdown circuit (TSD circuit) is designed only to shut the IC off to prevent thermal runaway. It is not designed to protect the IC or guarantee its operation. Do not continue to use the IC after operating this circuit or use the IC in an environment where the operation of this circuit is assumed.

| | TSD ON Temp. [°C] (typ.) | Hysteresis Temp. [°C] (typ.) |
|------------|--------------------------|------------------------------|
| BD95500MUV | 175 | 15 |

(10) Testing on application boards

When testing the IC on an application board, connecting a capacitor to a pin with low impedance subjects the IC to stress. Always discharge capacitors after each process or step. Always turn the IC's power supply off before connecting it to or removing it from a jig or fixture during the inspection process. Ground the IC during assembly steps as an antistatic measure. Use similar precaution when transporting or storing the IC.

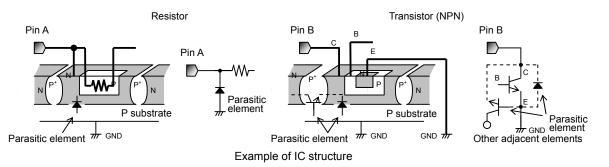
(11) Regarding input pin of the IC

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of these P layers with the N layers of other elements, creating a parasitic diode or transistor. For example, the relation between each potential is as follows:

OWhen GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode.

OWhen GND > Pin B, the P-N junction operates as a parasitic transistor.

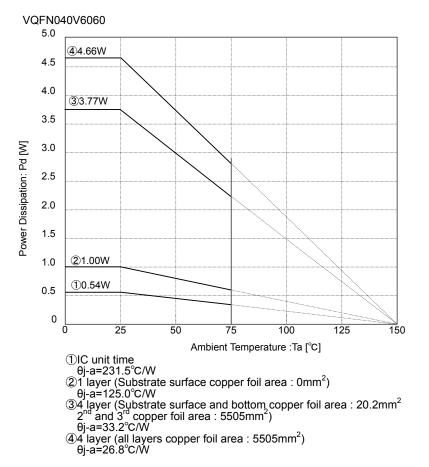
Parasitic diodes can occur inevitable in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Accordingly, methods by which parasitic diodes operate, such as applying a voltage that is lower than the GND (P substrate) voltage to an input pin, should not be used.



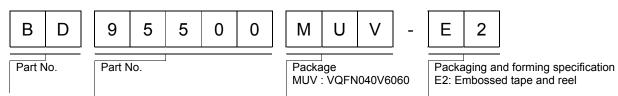
(12) Ground Wiring Pattern

When using both small signal and large current GND patterns, it is recommended to isolate the two ground patterns, placing a single ground point at the ground potential of application so that the pattern wiring resistance and voltage variations caused by large currents do not cause variations in the small signal ground voltage. Be careful not to change the GND wiring pattern of any external components, either.

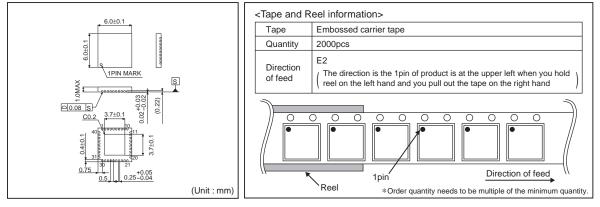
•Power Dissipation



Ordering part number



VQFN040V6060



| | g or reproduction of this document, in part or in whole, is permitted without the ROHM Co.,Ltd. |
|-------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| The conter | nt specified herein is subject to change for improvement without notice. |
| "Products | nt specified herein is for the purpose of introducing ROHM's products (hereinafter). If you wish to use any such Product, please be sure to refer to the specifications be obtained from ROHM upon request. |
| illustrate tl | of application circuits, circuit constants and any other information contained herein ne standard usage and operations of the Products. The peripheral conditions must nto account when designing circuits for mass production. |
| However, | was taken in ensuring the accuracy of the information specified in this document should you incur any damage arising from any inaccuracy or misprint of such n, ROHM shall bear no responsibility for such damage. |
| examples implicitly, a other part | cal information specified herein is intended only to show the typical functions of and of application circuits for the Products. ROHM does not grant you, explicitly of any license to use or exercise intellectual property or other rights held by ROHM and es. ROHM shall bear no responsibility whatsoever for any dispute arising from the h technical information. |
| equipment | cts specified in this document are intended to be used with general-use electronic or devices (such as audio visual equipment, office-automation equipment, commu- evices, electronic appliances and amusement devices). |
| The Produ | cts specified in this document are not designed to be radiation tolerant. |
| | IM always makes efforts to enhance the quality and reliability of its Products, a ay fail or malfunction for a variety of reasons. |
| against the failure of a shall bear | sure to implement in your equipment using the Products safety measures to guard e possibility of physical injury, fire or any other damage caused in the event of the ny Product, such as derating, redundancy, fire control and fail-safe designs. ROHM no responsibility whatsoever for your use of any Product outside of the prescribed ot in accordance with the instruction manual. |
| system wh may result instrument controller of the Pro | cts are not designed or manufactured to be used with any equipment, device or inch requires an extremely high level of reliability the failure or malfunction of which in a direct threat to human life or create a risk of human injury (such as a medica t, transportation equipment, aerospace machinery, nuclear-reactor controller, fuel- or other safety device). ROHM shall bear no responsibility in any way for use of any ducts for the above special purposes. If a Product is intended to be used for any ial purpose, please contact a ROHM sales representative before purchasing. |
| be control | nd to export or ship overseas any Product or technology specified herein that may led under the Foreign Exchange and the Foreign Trade Law, you will be required to sense or permit under the Law. |



Thank you for your accessing to ROHM product informations. More detail product informations and catalogs are available, please contact us.

ROHM Customer Support System

http://www.rohm.com/contact/

Downloaded from Elcodis.com electronic components distributor